Low-power 2-input multiplexer Rev. 7 — 18 January 2013

Product data sheet

General description 1.

The 74AUP2G157 is a single 2-input multiplexer which select data from two data inputs (I0 and I1) under control of a common data select input (S). The state of the common data select input determines the particular register from which the data comes. The output (Y, Y) presents the selected data in the true (non-inverted) and complement form. The enable input (\overline{E}) is active LOW. When \overline{E} is HIGH, the output Y is forced LOW and the output Y is forced HIGH regardless of all other input conditions.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V. This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \ \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C





3. Ordering information

Table 1. Ordering	g information			
Type number	Package			
	Temperature range	Name	Description	Version
74AUP2G157DC	–40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74AUP2G157GT	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 \times 1.95 \times 0.5 mm	SOT833-1
74AUP2G157GF	–40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body $1.35 \times 1 \times 0.5$ mm	SOT1089
74AUP2G157GD	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body $3\times2\times0.5$ mm	SOT996-2
74AUP2G157GM	–40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 \times 1.6 \times 0.5 mm	SOT902-2
74AUP2G157GN	–40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body $1.2 \times 1.0 \times 0.35$ mm	SOT1116
74AUP2G157GS	–40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 \times 1.0 \times 0.35 mm	SOT1203

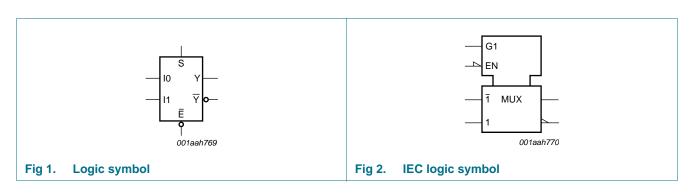
4. Marking

Table 2. Marking codes

Type number	Marking code ^[1]
74AUP2G157DC	a2P
74AUP2G157GT	a2P
74AUP2G157GF	aP
74AUP2G157GD	a2P
74AUP2G157GM	a2P
74AUP2G157GN	aP
74AUP2G157GS	aP

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

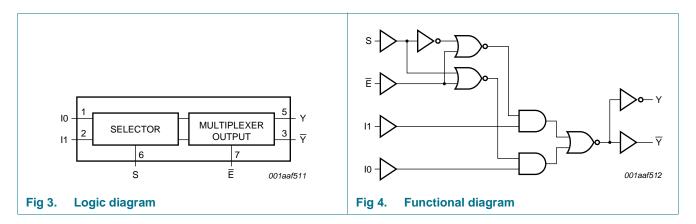
5. Functional diagram



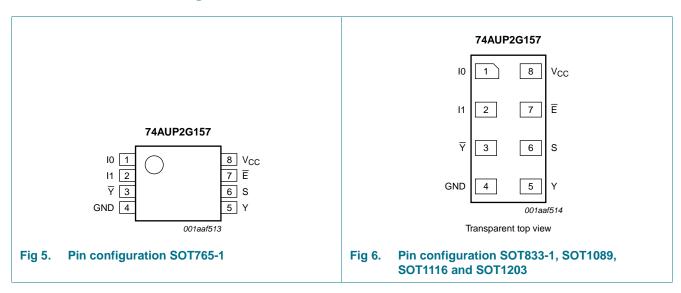
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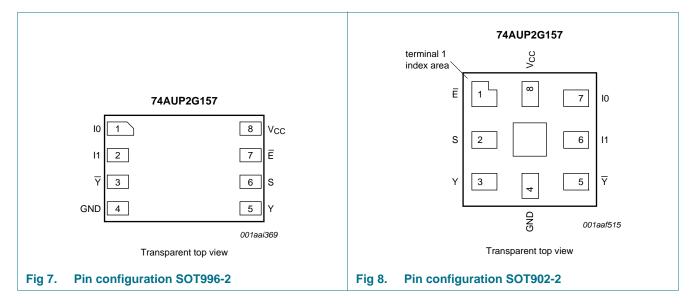


6. Pinning information



6.1 Pinning





6.2 Pin description

Symbol	Pin		Description
	SOT765-1, SOT833-1, SOT1089, SOT996-2, SOT1116 and SOT1203	SOT902-2	
10	1	7	data input from source 0
11	2	6	data input from source 1
Y	3	5	complement multiplexer output
GND	4	4	ground (0 V)
Y	5	3	true multiplexer output
S	6	2	data select input
Ē	7	1	enable input (active LOW)
V _{CC}	8	8	supply voltage

Functional description 7.

Function table^[1] Table 4.

Input		Output			
Ē	S	10	11	Y	Y
Н	Х	Х	Х	L	Н
L	L	L	Х	L	Н
L	L	Н	Х	Н	L
L	Н	Х	L	L	Н
L	Н	Х	Н	Н	L

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

					,
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode	<u>[1]</u> –0.5	+4.6	V
lo	output current	$V_{O} = 0 V$ to V_{CC}	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \text{ to } +125 \ ^{\circ}C$	[2] _	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For VSSOP8 packages: above 110 °C the value of Ptot derates linearly with 8.0 mW/K.

For XSON8 and XQFN8 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6.	Operating conditions				
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; $V_{CC} = 0 V$	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 0.8 V to 3.6 V	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70\times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30\times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.35\times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V_{CC} = 3.0 V to 3.6 V	-	-	0.9	V
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
√ _{ОН}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_O = –20 $\mu\text{A};V_{CC}$ = 0.8 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.75\times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.11	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.32	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	2.05	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.72	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 $\mu A; V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3\times V_{CC}$	V
		$I_0 = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.31	V
		I_{O} = 1.9 mA; V_{CC} = 1.65 V	-	-	0.31	V
		I_{O} = 2.3 mA; V_{CC} = 2.3 V	-	-	0.31	V
		I_{O} = 3.1 mA; V_{CC} = 2.3 V	-	-	0.44	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.31	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.44	V
l	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.1	μΑ
	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μΑ
∆l _{off}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μΑ
cc	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 0.8 \ V \ \text{to} \ 3.6 \ V \end{array}$	-	-	0.5	μA
∆l _{CC}	additional supply current		[1] -	-	40	μA
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V_{I} = GND or V_{CC}	-	0.6	-	pF
Co	output capacitance	$V_{O} = GND; V_{CC} = 0 V$	-	1.3	-	pF
T _{amb} = –	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70\times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.65\times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.0	-	-	V
VIL	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30\times V_{CC}$	V
		$V_{CC} = 0.9 \text{ V}$ to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V_{CC} = 3.0 V to 3.6 V	-	-	0.9	V

Table 7. Static characteristics ...continued

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{он}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = –20 $\mu A; V_{CC}$ = 0.8 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_0 = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.7\times V_{CC}$	-	-	V
		$I_0 = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.03	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.30	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 $\mu A; V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3\times V_{CC}$	V
		$I_0 = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.37	V
		I_{O} = 1.9 mA; V_{CC} = 1.65 V	-	-	0.35	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.33	V
		$I_0 = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.45	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.33	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.45	V
I.	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μΑ
OFF	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μΑ
∆l _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.6	μA
lcc	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \; A; \\ V_{CC} = 0.8 \; V \; to \; 3.6 \; V \end{array}$	-	-	0.9	μA
∆I _{CC}	additional supply current		<u>[1]</u> -	-	50	μA
Γ _{amb} = −	40 °C to +125 °C					
VIH	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.75 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9 \text{ V} \text{ to } 1.95 \text{ V}$	$0.70\times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	V
/ _{IL}	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.25\times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.30\times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V

Table 7. Static characteristics ... continued

Unit

V

V

V

V

V

V

V

V

V

V

v

V

V

V

V

μΑ

μΑ

μΑ

μΑ

μA

 $0.33 \times V_{CC}$ V

0.41

0.39

0.36

0.50

0.36

0.50

±0.75

±0.75

 ± 0.75

1.4

75

-

-

-

-

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<u>[1]</u> _

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Static characteristics ... continued Table 7. At recommended operating conditions; voltages are referenced to GND (ground = 0 V). Symbol Parameter Conditions Min Max Тур HIGH-level output voltage $V_{I} = V_{IH} \text{ or } V_{II}$ VOH I_O = –20 $\mu A; \, V_{CC}$ = 0.8 V to 3.6 V $V_{CC} - 0.11$ -_ $I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ $0.6 \times V_{CC}$ -- $I_0 = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ 0.93 -- $I_0 = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ 1.17 _ - $I_{O} = -2.3 \text{ mA}; V_{OO} = 2.3 \text{ V}$ 1.77 _ - $I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ 1.67 -- $I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ 2.40 -_ $I_{O} = -4.0 \text{ mA}; V_{OO} = 3.0 \text{ V}$ 2.30 --V_{OL} LOW-level output voltage $V_I = V_{IH} \text{ or } V_{IL}$ $I_{O} = 20 \ \mu A$; $V_{CC} = 0.8 \ V$ to 3.6 V 0.11 --

I_O = 1.1 mA; V_{CC} = 1.1 V

 $I_0 = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$

 $I_0 = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$

 $I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$

 $I_0 = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$

 $I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$

I_O = 4.0 mA; V_{CC} = 3.0 V

 V_I or $V_O = 0$ V to 3.6 V;

 $V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$

 $V_{CC} = 0 V \text{ to } 0.2 V$

 $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ $V_I = V_{CC} - 0.6 V; I_O = 0 A;$

 $V_{CC} = 3.3 V$

 $V_{I} = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V

 V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V

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[1] One input at V_{CC} – 0.6 V, other input at V_{CC} or GND.

input leakage current

additional power-off

leakage current

supply current

power-off leakage current

additional supply current

I₁

IOFF

Icc

 ΔI_{CC}

 ΔI_{OFF}

11. Dynamic characteristics

Table 8. Dynamic characteristics

Symbol	Parameter	Conditions		Tar	_{mb} = 25 °	°C	T _{amb} = ·	–40 °C to ·	+125 °C	Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Max (125 °C)	
C _L = 5 pl	F									
t _{pd}	propagation delay	I0, I1 to Y, \overline{Y} ; see Figure 9	[2]							
		$V_{CC} = 0.8 V$		-	21.2	-	-	-	-	ns
	V_{CC} = 1.1 V to 1.3 V		2.5	6.1	13.3	2.2	13.8	13.9	ns	
	V_{CC} = 1.4 V to 1.6 V		1.9	4.2	7.8	2.0	8.4	8.8	ns	
	V_{CC} = 1.65 V to 1.95 V		1.7	3.4	6.2	1.6	6.9	7.3	ns	
	V_{CC} = 2.3 V to 2.7 V		1.5	2.7	4.3	1.2	4.9	5.2	ns	
	V_{CC} = 3.0 V to 3.6 V		1.3	2.4	3.7	1.0	4.0	4.2	ns	
	S to Y, \overline{Y} ; see Figure 9	[2]								
		$V_{CC} = 0.8 V$		-	23.6	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		2.6	6.6	13.8	2.2	14.3	14.5	ns
		V_{CC} = 1.4 V to 1.6 V		1.9	4.5	8.0	2.1	8.7	9.1	ns
		V_{CC} = 1.65 V to 1.95 V		1.7	3.6	6.3	1.6	7.0	7.4	ns
		V_{CC} = 2.3 V to 2.7 V		1.6	2.8	4.4	1.2	5.0	5.3	ns
		V_{CC} = 3.0 V to 3.6 V		1.3	2.5	3.7	1.0	4.0	4.2	ns
		\overline{E} to Y, \overline{Y} ; see Figure 10	[2]							
		$V_{CC} = 0.8 V$		-	22.6	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		2.7	6.4	13.7	2.5	14.3	14.5	ns
		V_{CC} = 1.4 V to 1.6 V		2.1	4.4	8.0	2.1	8.7	9.1	ns
		V_{CC} = 1.65 V to 1.95 V		1.8	3.6	6.3	1.6	7.0	7.4	ns
		V_{CC} = 2.3 V to 2.7 V		1.6	2.8	4.2	1.4	4.8	5.1	ns
		V_{CC} = 3.0 V to 3.6 V		1.4	2.5	3.6	1.1	3.9	4.2	ns

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Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T _{amb} =	-40 °C to	+125 °C	Unit
			Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	_
C _L = 10	ρΈ								
t _{pd}	propagation delay	I0, I1 to Y, \overline{Y} ; see Figure 9 [2]							
		$V_{CC} = 0.8 V$	-	24.5	-	-	-	-	ns
	$V_{CC} = 1.1 \text{ V} \text{ to } 1.3 \text{ V}$	2.9	6.9	15.1	2.5	15.6	15.8	ns	
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	2.2	4.8	8.9	2.4	9.6	10.0	ns
	V _{CC} = 1.65 V to 1.95 V	2.1	4.0	7.1	1.9	7.9	8.3	ns	
	V_{CC} = 2.3 V to 2.7 V	1.9	3.2	5.0	1.6	5.7	6.0	ns	
		V_{CC} = 3.0 V to 3.6 V	1.7	2.9	4.4	1.3	4.7	5.0	ns
		S to Y, Y; see Figure 9 [2]							
		$V_{CC} = 0.8 V$	-	27.2	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V	3.0	7.4	15.5	2.6	16.1	16.4	ns
		V_{CC} = 1.4 V to 1.6 V	2.3	5.1	9.0	2.4	9.8	10.3	ns
		V_{CC} = 1.65 V to 1.95 V	2.1	4.2	7.2	1.9	8.0	8.4	ns
		V_{CC} = 2.3 V to 2.7 V	1.9	3.4	5.1	1.6	5.7	6.1	ns
		V_{CC} = 3.0 V to 3.6 V	1.7	3.0	4.4	1.4	4.7	5.0	ns
		\overline{E} to Y, \overline{Y} ; see <u>Figure 10</u> [2]							
		$V_{CC} = 0.8 V$	-	25.9	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V	3.1	7.2	15.5	2.8	16.1	16.4	ns
		V_{CC} = 1.4 V to 1.6 V	2.5	5.0	9.0	2.4	9.8	10.3	ns
		V_{CC} = 1.65 V to 1.95 V	2.2	4.1	7.1	1.9	8.0	8.4	ns
		V_{CC} = 2.3 V to 2.7 V	1.9	3.3	4.9	1.7	5.5	5.9	ns
		V_{CC} = 3.0 V to 3.6 V	1.7	3.0	4.2	1.5	4.6	4.8	ns

Table 8. Dynamic characteristics ...continued

Low-power 2-input multiplexer

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T _{amb} =	–40 °C to	+125 °C	Unit
			Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	_
C _L = 15	ρF			1					
t _{pd}	propagation delay	I0, I1 to Y, \overline{Y} ; see Figure 9 [2]							
		$V_{CC} = 0.8 V$	-	27.8	-	-	-	-	ns
	$V_{CC} = 1.1 \text{ V} \text{ to } 1.3 \text{ V}$	3.3	7.7	16.8	2.8	17.4	17.6	ns	
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	2.5	5.4	9.8	2.7	10.6	11.2	ns
	V _{CC} = 1.65 V to 1.95 V	2.4	4.4	7.8	2.2	8.7	9.2	ns	
	V_{CC} = 2.3 V to 2.7 V	2.2	3.7	5.6	1.9	6.4	6.7	ns	
		V_{CC} = 3.0 V to 3.6 V	2.0	3.4	4.9	1.6	5.3	5.6	ns
		S to Y, Y; see Figure 9 [2]							
		$V_{CC} = 0.8 V$	-	30.7	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V}$ to 1.3 V	3.3	8.2	17.2	2.9	17.9	18.2	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	2.6	5.7	10.0	2.7	10.9	11.4	ns
		V_{CC} = 1.65 V to 1.95 V	2.4	4.7	7.9	2.2	8.9	9.4	ns
		V_{CC} = 2.3 V to 2.7 V	2.2	3.8	5.7	1.9	6.5	6.8	ns
		V_{CC} = 3.0 V to 3.6 V	2.0	3.5	5.0	1.6	5.4	5.7	ns
		\overline{E} to Y, \overline{Y} ; see <u>Figure 10</u> [2]							
		$V_{CC} = 0.8 V$	-	29.1	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V}$ to 1.3 V	3.5	8.0	17.2	3.1	17.9	18.2	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	2.8	5.6	9.9	2.7	10.9	11.4	ns
		V_{CC} = 1.65 V to 1.95 V	2.4	4.6	7.9	2.2	8.9	9.4	ns
		V_{CC} = 2.3 V to 2.7 V	2.2	3.8	5.5	2.0	6.2	6.6	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	3.4	4.7	1.8	5.1	5.4	ns

Table 8. Dynamic characteristics ...continued

Low-power 2-input multiplexer

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T _{amb} = -40 °C to +125 °C			Unit
			Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	_
C _L = 30	ρF						•		•
t _{pd}	propagation delay	I0, I1 to Y, \overline{Y} ; see Figure 9 [2]							
		V _{CC} = 0.8 V	-	35.4	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V} \text{ to } 1.3 \text{ V}$	4.3	9.8	21.6	3.7	22.5	22.8	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	3.3	6.9	12.4	3.4	13.6	14.4	ns
		V_{CC} = 1.65 V to 1.95 V	3.1	5.7	10.0	2.8	11.3	11.9	ns
		V_{CC} = 2.3 V to 2.7 V	2.9	4.8	7.2	2.6	8.2	8.7	ns
		V_{CC} = 3.0 V to 3.6 V	2.8	4.4	6.4	2.3	6.9	7.3	ns
		S to Y, Y; see Figure 9 [2]							
		$V_{CC} = 0.8 V$	-	38.8	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V	4.4	10.5	22.0	3.7	23.0	23.4	ns
		V_{CC} = 1.4 V to 1.6 V	3.3	7.2	12.6	3.5	13.9	14.6	ns
		V_{CC} = 1.65 V to 1.95 V	3.1	5.9	10.1	2.8	11.4	12.0	ns
		V_{CC} = 2.3 V to 2.7 V	2.9	4.9	7.3	2.6	8.3	8.7	ns
		V_{CC} = 3.0 V to 3.6 V	2.7	4.5	6.4	2.3	6.9	7.3	ns
		\overline{E} to Y, \overline{Y} ; see <u>Figure 10</u> [2]							
		$V_{CC} = 0.8 V$	-	36.8	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V	4.4	10.1	22.1	3.9	23.0	23.4	ns
		V_{CC} = 1.4 V to 1.6 V	3.6	7.1	12.6	3.5	13.8	14.6	ns
		V_{CC} = 1.65 V to 1.95 V	3.1	5.8	10.0	2.8	11.3	12.0	ns
		V_{CC} = 2.3 V to 2.7 V	2.9	4.9	7.1	2.7	8.0	8.5	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.7	4.5	6.2	2.4	6.7	7.0	ns

Table 8. Dynamic characteristics ...continued

Low-power 2-input multiplexer

Table 8.	Dynamic	characteristics	continued
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Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 11</u>.

Symbol	Parameter	Conditions		T _{amb} = 25 °C		T _{amb} = -40 °C to +125 °C			Unit	
				Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	
C _L = 5 pl	F, 10 pF, 15 pF and	30 pF						•		
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz};$ V _I = GND to V _{CC}	<u>[3]</u>							
		$V_{CC} = 0.8 V$		-	5.2	-	-	-	-	pF
		V_{CC} = 1.1 V to 1.3 V		-	5.5	-	-	-	-	pF
		V_{CC} = 1.4 V to 1.6 V		-	5.7	-	-	-	-	pF
		V_{CC} = 1.65 V to 1.95 V		-	6.0	-	-	-	-	pF
		V_{CC} = 2.3 V to 2.7 V		-	6.9	-	-	-	-	pF
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		-	7.9	-	-	-	-	pF

[1] All typical values are measured at nominal V_{CC} .

[2] t_{pd} is the same as t_{PLH} and t_{PHL}

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $\mathsf{P}_{\mathsf{D}} = \mathsf{C}_{\mathsf{P}\mathsf{D}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}^2 \times \mathsf{f}_i \times \mathsf{N} + \Sigma(\mathsf{C}_{\mathsf{L}} \times \mathsf{V}_{\mathsf{C}\mathsf{C}}^2 \times \mathsf{f}_o) \text{ where:}$

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

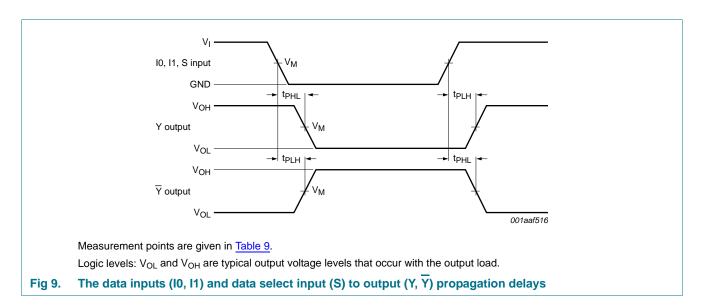
 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

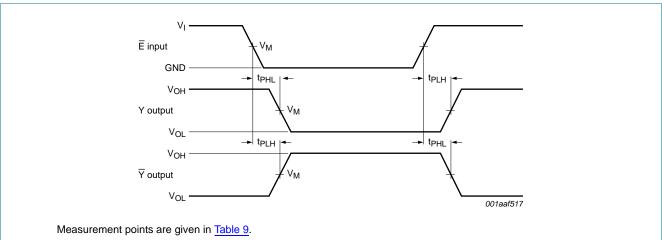
12. Waveforms



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Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 10. The enable input (\overline{E}) to output (Y, \overline{Y}) propagation delays

Table 9. Measurement points

Supply voltage	Output	Input		
V _{cc}	V _M	V _M	VI	$t_r = t_f$
0.8 V to 3.6 V	$0.5 imes V_{CC}$	$0.5 imes V_{CC}$	V _{CC}	\leq 3.0 ns

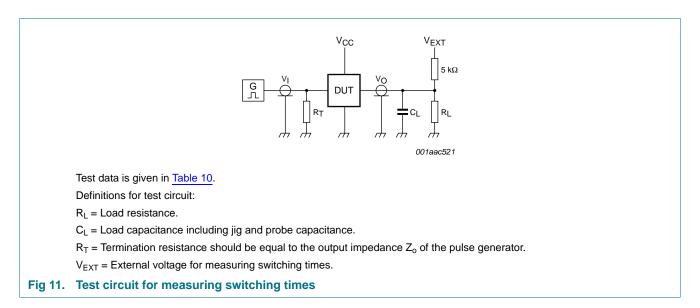


Table 10. Test data

Supply voltage	Load	V _{EXT}			
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 k\Omega$, for measuring propagation delays, setup and hold times and pulse width $R_L = 1 M\Omega$.



13. Package outline

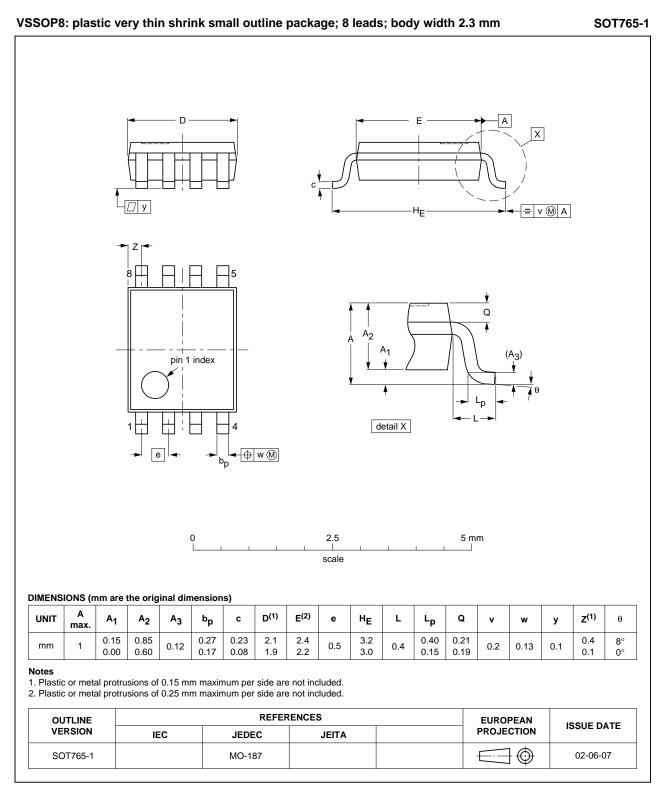


Fig 12. Package outline SOT765-1 (VSSOP8)

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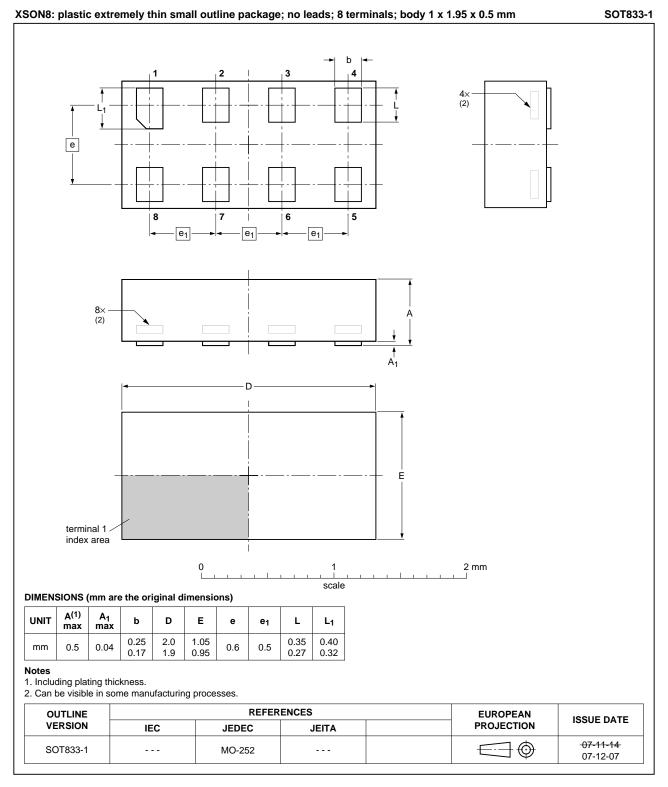
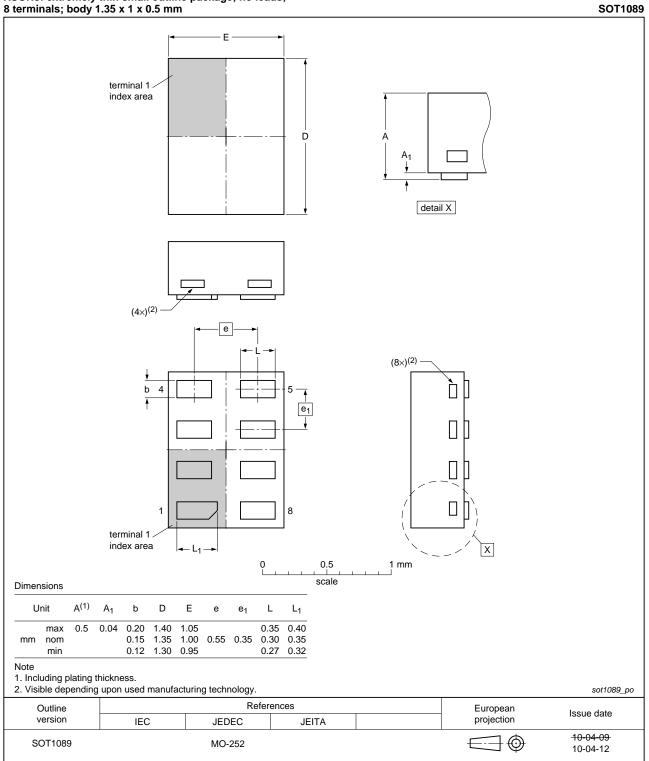


Fig 13. Package outline SOT833-1 (XSON8)

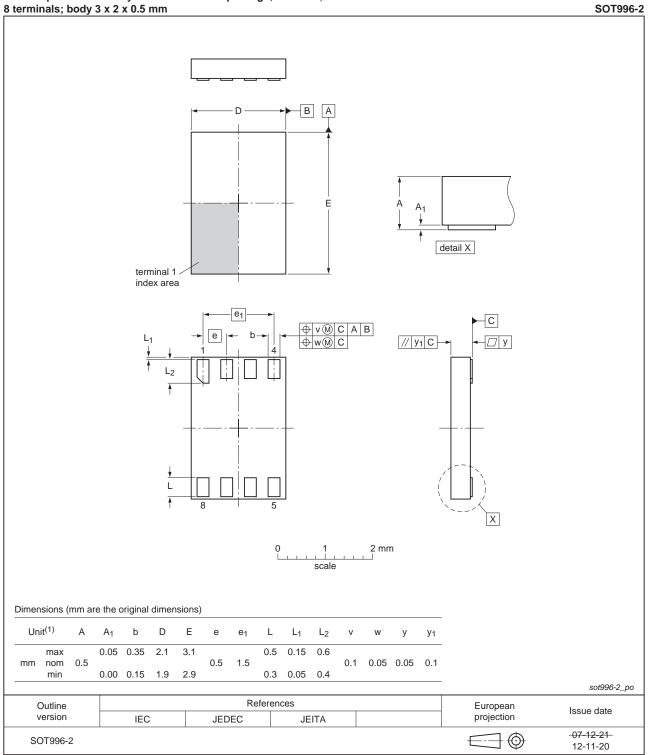


XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm

Fig 14. Package outline SOT1089 (XSON8)

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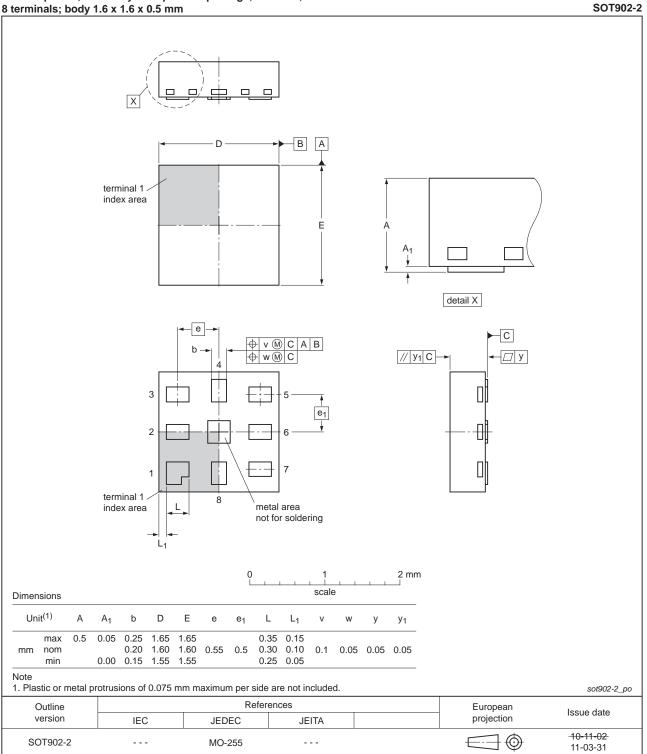




XSON8: plastic extremely thin small outline package; no leads; 8 terminals: body 3 x 2 x 0.5 mm

Fig 15. Package outline SOT996-2 (XSON8)

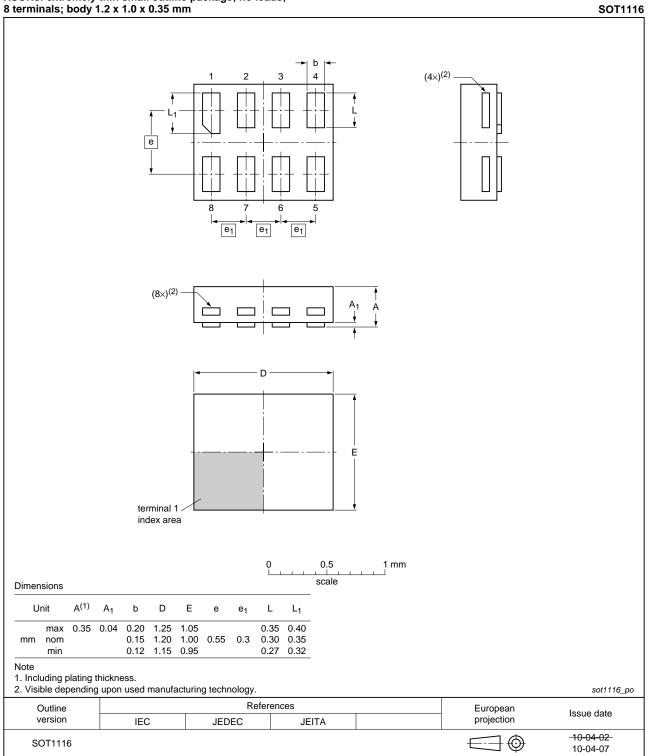




XQFN8: plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 x 1.6 x 0.5 mm

Fig 16. Package outline SOT902-2 (XQFN8)

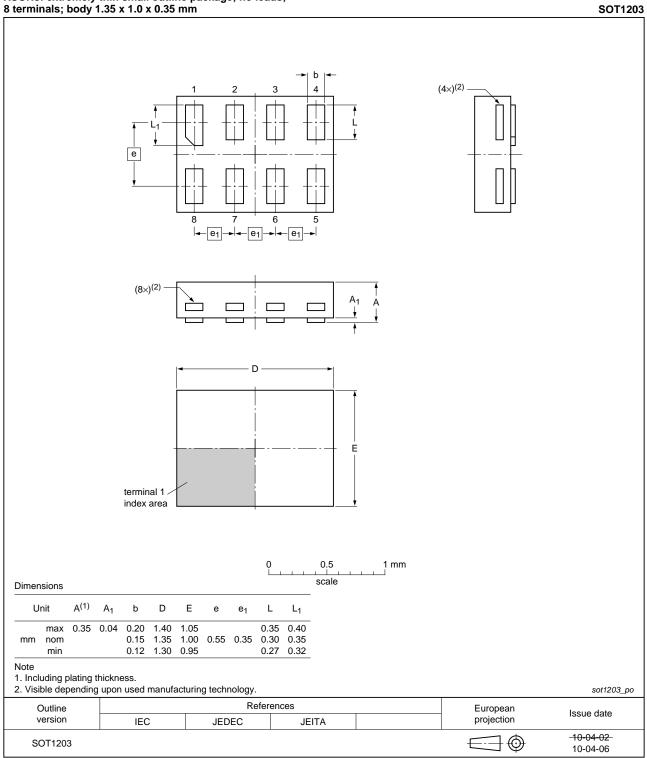
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XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm

Fig 17. Package outline SOT1116 (XSON8)

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XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1.0 x 0.35 mm

Fig 18. Package outline SOT1203 (XSON8)



14. Abbreviations

AcronymDescriptionCDMCharged Device ModelDUTDevice Under TestESDElectroStatic DischargeHBMHuman Body ModelMMMachine Model	Table 11. Abbreviations					
DUTDevice Under TestESDElectroStatic DischargeHBMHuman Body Model	Acronym	Description				
ESD ElectroStatic Discharge HBM Human Body Model	CDM	Charged Device Model				
HBM Human Body Model	DUT	Device Under Test				
	ESD	ElectroStatic Discharge				
MM Machine Model	HBM	Human Body Model				
	MM	Machine Model				

15. Revision history

Document IDRelease dateData sheet statusChange noticeSupersedes74AUP2G157 v.720130118Product data sheet-74AUP2G157 v.6Modifications:• For type number 74AUP2G157GD XSON8U has changed to XSON8.74AUP2G157 v.620120606Product data sheet-74AUP2G157 v.574AUP2G157 v.520111205Product data sheet-74AUP2G157 v.474AUP2G157 v.420100730Product data sheet-74AUP2G157 v.374AUP2G157 v.320080702Product data sheet-74AUP2G157 v.274AUP2G157 v.220080219Product data sheet-74AUP2G157 v.1	Table 12. Revision his	tory			
Modifications: • For type number 74AUP2G157GD XSON8U has changed to XSON8. 74AUP2G157 v.6 20120606 Product data sheet - 74AUP2G157 v.5 74AUP2G157 v.5 20111205 Product data sheet - 74AUP2G157 v.4 74AUP2G157 v.4 20100730 Product data sheet - 74AUP2G157 v.3 74AUP2G157 v.3 20080702 Product data sheet - 74AUP2G157 v.2 74AUP2G157 v.2 20080219 Product data sheet - 74AUP2G157 v.1	Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP2G157 v.6 20120606 Product data sheet - 74AUP2G157 v.5 74AUP2G157 v.5 20111205 Product data sheet - 74AUP2G157 v.4 74AUP2G157 v.4 20100730 Product data sheet - 74AUP2G157 v.3 74AUP2G157 v.3 20080702 Product data sheet - 74AUP2G157 v.2 74AUP2G157 v.2 20080219 Product data sheet - 74AUP2G157 v.1	74AUP2G157 v.7	20130118	Product data sheet	-	74AUP2G157 v.6
74AUP2G157 v.5 20111205 Product data sheet - 74AUP2G157 v.4 74AUP2G157 v.4 20100730 Product data sheet - 74AUP2G157 v.3 74AUP2G157 v.3 20080702 Product data sheet - 74AUP2G157 v.2 74AUP2G157 v.2 20080219 Product data sheet - 74AUP2G157 v.2 74AUP2G157 v.2 20080219 Product data sheet - 74AUP2G157 v.1	Modifications:	 For type nur 	nber 74AUP2G157GD XSON	3U has changed to X	(SON8.
74AUP2G157 v.4 20100730 Product data sheet - 74AUP2G157 v.3 74AUP2G157 v.3 20080702 Product data sheet - 74AUP2G157 v.2 74AUP2G157 v.2 20080219 Product data sheet - 74AUP2G157 v.2	74AUP2G157 v.6	20120606	Product data sheet	-	74AUP2G157 v.5
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74AUP2G157 v.2 20080219 Product data sheet - 74AUP2G157 v.1	74AUP2G157 v.4	20100730	Product data sheet	-	74AUP2G157 v.3
	74AUP2G157 v.3	20080702	Product data sheet	-	74AUP2G157 v.2
	74AUP2G157 v.2	20080219	Product data sheet	-	74AUP2G157 v.1
74AUP2G157 v.1 20061006 Product data sheet	74AUP2G157 v.1	20061006	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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Low-power 2-input multiplexer

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